

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re PATENT application of	)	Confirmation No. 8307
Masahiro KUME et al.	)	Art Unit: 2828
Application No. 09/504,782	)	Examiner: Delma R. Flores Ruiz
Patent No. 7,212,556 B1	)	
Issued: May 1, 2007	)	
Filed: February 15, 2000	)	
For: SEMICONDUCTOR LASER DEVICE OPTICAL	)	
DISK APPARATUS AND OPTICAL INTEGRATED UNIT	)	

**REQUEST FOR CERTIFICATE OF CORRECTION – USPTO MISTAKE**

**Certificate of Corrections Branch**

Commissioner for Patents

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

In reviewing the above-identified patent, a typographical USPTO printing error was discovered therein requiring correction in order to conform to the Official Record in the application. None of the below corrections should be considered substantive in nature, but instead merely correct obvious errors therein.

The errors noted are set forth on the attached copy of Form PTO-1050 (Rev. 3-82) in the manner required by the Commissioner's Notice.

Specifically, upon reviewing the claims 1, 8 and 9 of the issued patent the errors in the attached form were noted. These errors occurred as a result of a USPTO printing error of U.S. Patent No. 7,212,556 B1.

Applicants respectfully submit that corrections to the claims 1, 8 and 9 are supported by Amendment After Final Rejection filed by Applicants' representative on August 7, 2006.

Since this error was a result of an error on the part of the USPTO, no fees associated with the Certificate of Correction are believed to be due at this time. However, the Commissioner is hereby authorized to charge any fees connected with this filing which may be required now, or credit any overpayment to Deposit Account No. 19-2380.

Respectfully submitted,

**NIXON PEABODY LLP**

/Jeffrey L. Costellia, Reg.#35483/

Jeffrey L. Costellia

Registration No. 35,483

**NIXON PEABODY LLP**  
**CUSTOMER NO. 22204**

401 9th St., N.W.

Suite 900

Washington, DC 20004

Phone: 202-585-8000

UNITED STATES PATENT AND TRADEMARK OFFICE

**CERTIFICATE OF CORRECTION**

PATENT NO. : 7,212,556

ISSUED : May 1, 2007

INVENTOR(S) : Masahiro KUME, et al.

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

in the claims,

claim 1, column 23, line 24, " $\text{In}_x\text{Ga}_{1-x}\text{N}$ " should read " $\text{In}_y\text{Ga}_{1-y}\text{N}$ ."

claim 8, column 24, line 24, " $\text{In}_x\text{Ga}_{1-x}\text{N}$ " should read " $\text{In}_y\text{Ga}_{1-y}\text{N}$ ."

claim 9, column 24, lines 27-29, "a contact layer, which is made of a nitride semiconductor of a first conductivity type and is formed over a substrate;" should be removed.

claim 9, column 24, line 32, "contact layer" should read "substrate"

claim 9, column 24, line 37, "over the active layer; and" should read "over the active layer;"

claim 9, column 24, between line 37 and 38, "an electrode formed over the second cladding layer; and" should be added.

claim 9, column 24, line 38, "the first conductivity type" should read "the second conductivity type"

claim 9, column 24, line 39, "the substrate and" should be removed.

claim 9, column 24, line 39, "the first cladding layer" should read "the second cladding layer."

claim 9, column 24, line 39, after "the first cladding layer" add "and the electrode"

MAILING ADDRESS OF SENDER:  
NIXON PEABODY LLP  
401 9<sup>th</sup> Street, N.W., Suite 900  
Washington, D.C. 20004-2128

PATENT NO. 7,212,556

SEND TO: Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450